

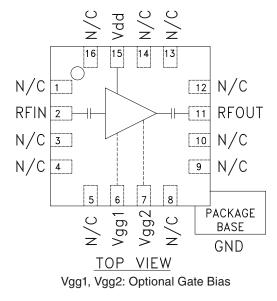


Typical Applications

The HMC441LP3 / HMC441LP3E is a medium PA for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- VSAT
- LO Driver for HMC Mixers
- Military EW & ECM

Functional Diagram



HMC441LP3 / 441LP3E

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

Features

Gain: 14 dB Saturated Power: +20 dBm @ 20% PAE Single Supply Voltage: +5V w/ Optional Gate Bias 50 Ohm Matched Input/Output

16 Lead 3x3mm SMT Package: 9mm²

General Description

The HMC441LP3 & HMC441LP3E are broadband GaAs PHEMT MMIC Medium Power Amplifiers which operate between 6.5 and 13.5 GHz. The leadless plastic QFN surface mount packaged amplifier provides 14 dB of gain, +20 dBm saturated power at 20% PAE from a +5V supply voltage. An optional gate bias is provided to allow adjustment of gain, RF output power, and DC power dissipation. This 50 Ohm matched amplifier does not require any external components making it an ideal linear gain block or driver for HMC SMT mixers.

Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vdd = 5V, Vgg1 = Vgg2 = Open

- 4										
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	6.5 - 8.0		8.0 - 11.0		11.0 - 13.5			GHz		
Gain	10	13		12	14		10	13		dB
Gain Variation Over Temperature		0.02	0.025		0.02	0.025		0.02	0.025	dB/ °C
Input Return Loss		12			15			14		dB
Output Return Loss		12			15			13		dB
Output Power for 1 dB Compression (P1dB)	13	16		15	18		14	17		dBm
Saturated Output Power (Psat)		18.5			20			19.5		dBm
Output Third Order Intercept (IP3)	23	26		26	29		26	29		dBm
Noise Figure		5.0			4.5			4.75		dB
Supply Current (Idd)		90	115		90	115		90	115	mA

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HMC441LP3 / 441LP3E

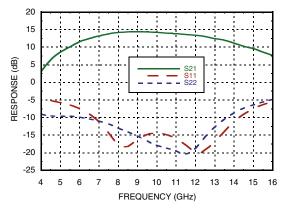
GaAs pHEMT MMIC MEDIUM

POWER AMPLIFIER, 6.5 - 13.5 GHz

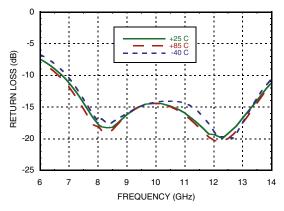
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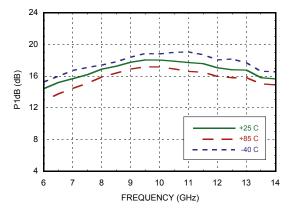
Broadband Gain & Return Loss



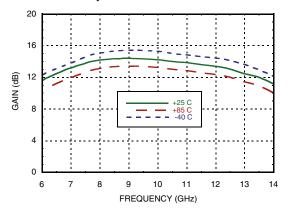
Input Return Loss vs. Temperature



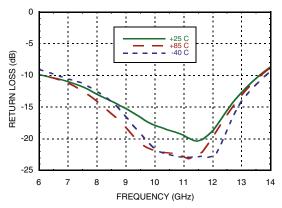
P1dB vs. Temperature



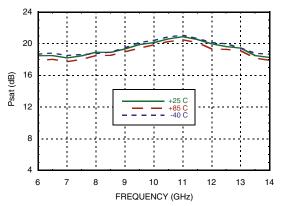
Gain vs. Temperature



Output Return Loss vs. Temperature



Psat vs. Temperature

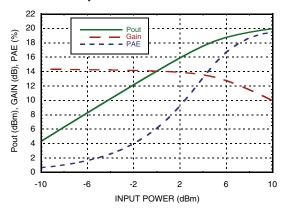


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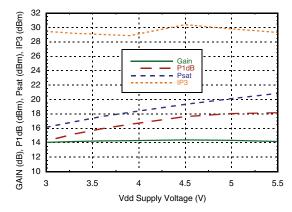




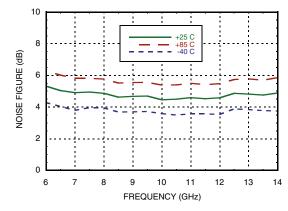
Power Compression @ 10 GHz

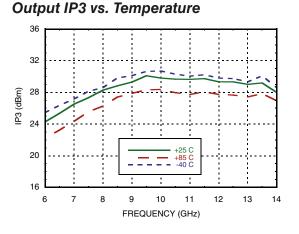


Gain, Power & Output IP3 vs. Supply Voltage @ 10 GHz



Noise Figure vs. Temperature



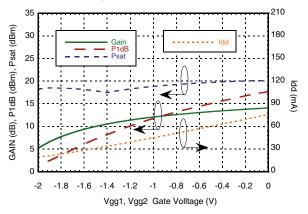


HMC441LP3 / 441LP3E

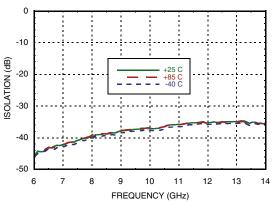
GaAs pHEMT MMIC MEDIUM

POWER AMPLIFIER, 6.5 - 13.5 GHz

Gain, Power & Idd vs. Gate Voltage @ 10 GHz



Reverse Isolation vs. Temperature



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Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+6 Vdc		
Dialii Bias voltage (vuu)	+0 VUC		
Gate Bias Voltage (Vgg1,Vgg2)	-8 to 0 Vdc		
RF Input Power (RFIN)(Vdd = +5 Vdc)	+15 dBm		
Channel Temperature	175 °C		
Continuous Pdiss (T = 85 °C) (derate 8.5 mW/°C above 85 °C)	0.76 W		
Thermal Resistance (channel to ground paddle)	118.2 °C/W		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-40 to +85 °C		

HMC441LP3 / 441LP3E

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

Typical Supply Current vs. Vdd

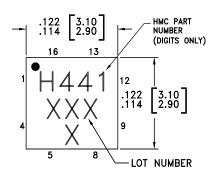
Vdd (V)	ldd (mA)
+5.5	92
+5.0	90
+4.5	88
+3.3	83
+3.0	82

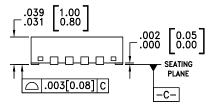
Note: Amplifier will operate over full voltage range shown above

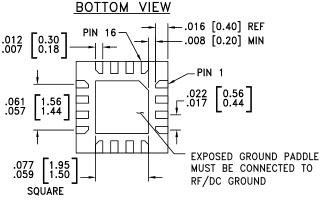


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing







NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY

- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]	
HMC441LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	441 XXXX	
HMC441LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	441 XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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HMC441LP3 / 441LP3E

v05.0812



GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3-5, 8-10, 12-14, 16	N/C	This pin may be connected to RF/DC ground.	
2	RFIN	This pin is AC coupled and matched to 50 Ohms.	
6, 7	Vgg1, Vgg2	Optional gate control for amplifier. If left open, the amplifier will run at standard current. Negative voltage applied will reduce current.	Vgg1 Vgg2
11	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
15	Vdd	Power Supply Voltage for the amplifier. An external bypass capacitor of 100 pF is required.	OVdd ↓ ↓ ↓ ↓ ↓
	GND	Package bottom must be connected to RF/DC ground.	

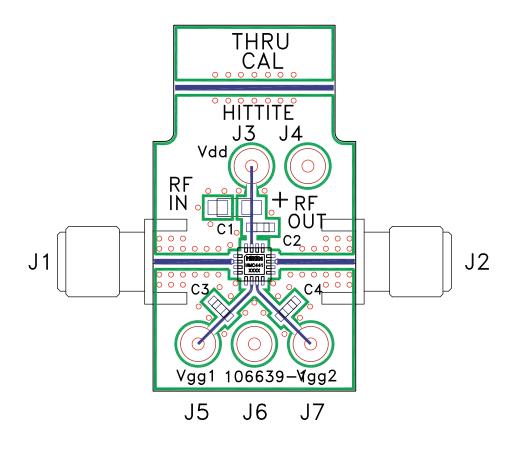


HMC441LP3 / 441LP3E

GaAs pHEMT MMIC MEDIUM POWER AMPLIFIER, 6.5 - 13.5 GHz



Evaluation PCB



List of Materials for Evaluation PCB 106705 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J7	DC Pin
C1	4.7 µF Capacitor, Tantalum
C2 - C4	100 pF Capacitor, 0402 Pkg.
U1	HMC441LP3 / HMC441LP3E Amplifier
PCB [2]	106639 Evaluation PCB, 10 mils

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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